

Description

The XE23T24VU is a bi-directional ESD protection diode designed to protect sensitive electronic components which are connected to low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning.

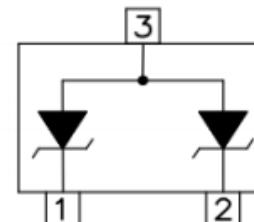
The XE23T24VU may be used to provide ESD protection up to $\pm 30\text{kV}$ contact and $\pm 30\text{kV}$ air discharge according to IEC61000-4-2, and withstand peak pulse current up to 5A (8/20 μs) according to IEC61000-4-5.

The XE23T24VU is available in SOT-23 package. Standard products are Pb-free and Halogen-free.

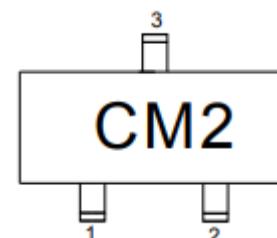
<http://www.xihangsemi.com>



SOT-23



Circuit Diagram



Marking (Top View)

Order Information

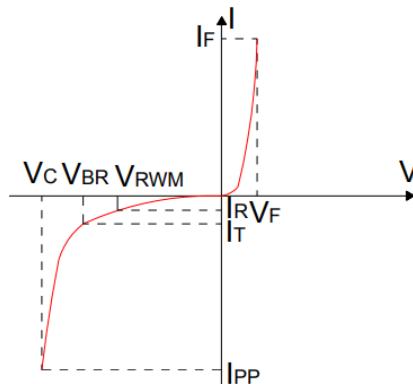
Device	Package	Shipping
XE23T24VU	SOT-23	3000/Tape&Reel

Applications

- ◆ Subscriber identify module (SIM) card protection
- ◆ Wireless bus protection
- ◆ Control & monitoring systems
- ◆ Portable electronics
- ◆ Servers, notebook and desktop
- ◆ Cellular handsets and accessories

Definitions of electrical characteristics

Symbol	Parameter
V_{RWM}	Reverse Stand-off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Reverse Breakdown Voltage @ I_T
I_R	Reverse Breakdown Current
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}



Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_P = 8/20\mu S$)	P_{PK}	270	W
Peak Pulse Current ($t_P = 8/20\mu S$)	I_{pp}	5	A
ESD according to IEC61000-4-2 air discharge	V_{ESD}	± 30	kV
ESD according to IEC61000-4-2 contact discharge		± 30	kV
Lead Soldering Temperature	T_L	260 (10 sec)	°C
Operating Temperature	T_{OP}	-55 to +125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

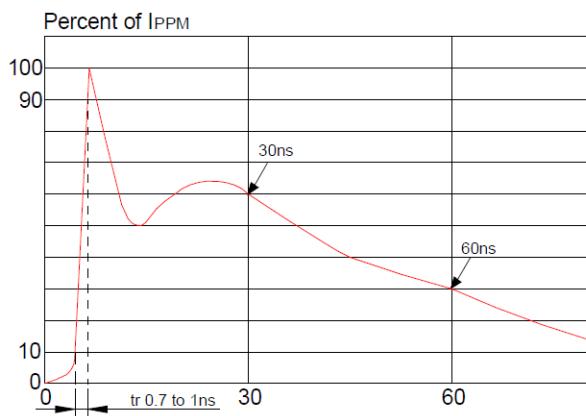
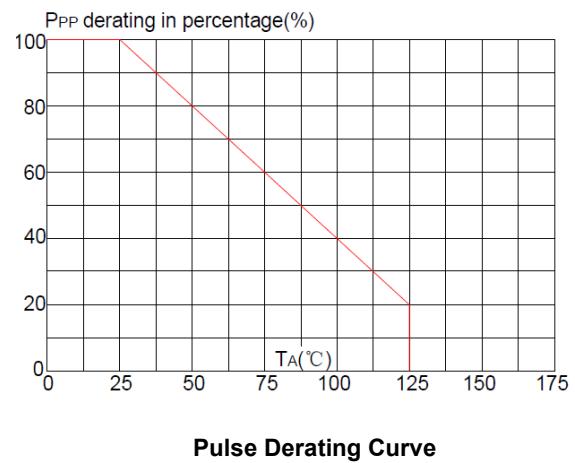
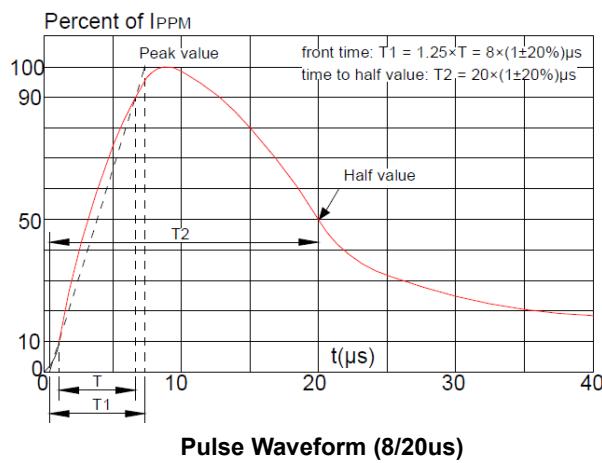
Electrical Characteristics ($T_a=25^\circ C$, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Stand-off Voltage	V_{RWM}				24	V
Reverse Leakage Current	I_R	$V_{RWM} = 24V$			1	uA
Reverse Breakdown Voltage	V_{BR}	$I_T = 1mA$	26.7			V
Clamping Voltage ¹⁾	V_{CL}	$I_{PP}=1A \quad t_P = 8/20\mu s$			43	V
		$I_{PP}=5A \quad t_P = 8/20\mu s$			55	V
Junction Capacitance	C_J	$V_R=0V \quad f = 1MHz$	150	180		pF

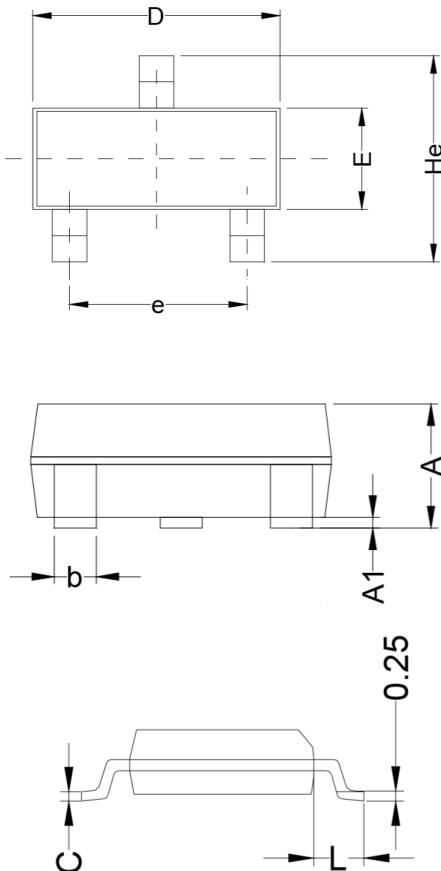
Notes:

1)Non-repetitive current pulse, according to IEC61000-4-5.

Typical Characteristics (Ta=25°C, unless otherwise noted)

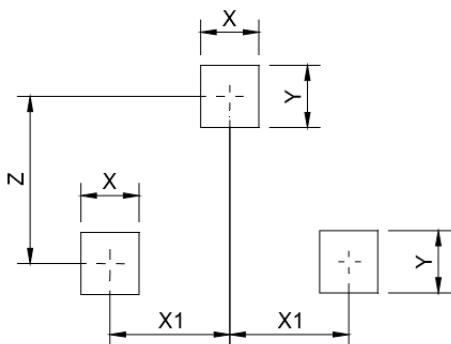


Package Outline Dimensions (SOT-23)



Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
b	0.25	0.325	0.010	0.013
C	0.22	0.25	0.009	0.010
D	2.80	3.00	0.110	0.118
E	1.80	1.90	0.071	0.075
E	1.20	1.40	0.047	0.055
L	0.30	0.50	0.012	0.020
He	2.25	2.25	0.089	0.100
X	0.80		0.031	
X1	0.95		0.037	
Y	0.80		0.031	
Z	2.02		0.080	

Recommend Land Pattern (Unit: mm)



Note: This recommended land pattern is for reference purpose only.

NOTICE

XIHANG's products are not authorized for use as components in any life support device or systems.

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